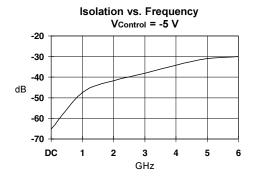


# **Product Description**

Stanford Microdevices' SSW-224 is a high perfomance Gallium Arsenide Field Effect Transistor MMIC switch housed in a low-cost surface-mountable 8-pin ceramic package.

This single-pole, double-throw, reflective switch consumes less than 50uA and operates at -5V and 0V for control bias. Its high isolation and low insertion loss makes it ideal for T/R switching in analog and digital wireless communication systems.

The die is fabricated using 0.5 micron FET process with gold metallization and silicon nitride passivation to achieve excellent performance and reliability.



# SSW-224

# DC-6 GHz High Isolation SPDT GaAs MMIC Switch



# **Product Features**

- High Isolation: 40dB at 2GHz, 30dB at 6GHz
- Low DC Power Consumption
- Broadband Performance True DC Operation
- Low Cost Surface-Mountable Ceramic Package

# **Applications**

- Analog/Digital Wireless System
- Spread Spectrum
- GPS

# Electrical Specifications at Ta = 25C

Symbol	Parameters: Test Conditions: Zo=50ohms		Units	Min.	Тур.	Max.
Ins	Insertion Loss	f = 0.05-2.0GHz f = 2.00-4.0GHz f = 4.05-6.0GHz	dB dB dB		0.7 1.1 1.5	1.1 1.5
Isol	Isolation	f = 0.05-2.0GHz f = 2.00-4.0GHz f = 4.00-6.0GHz	dB dB dB	37 30 27	47 40 35	
VSWR on	Input & Output VSWR (on or low loss state)	f = 0.05-2.0GHz f = 2.00-4.0GHz f = 4.00-6.0GHz			1.15 1.25 1.50	
P1dB	Output Power at 1dB Compression f= 0.5-6.0GHz	V = -5V V = -8V	dBm dBm		+26 +29	
TOIP	Third Order Intercept Point f= 0.5-6.0GHz	V = -5V V = -8V	dBm dBm		+45 +48	
ld	Device Current		uA		40	
lsw	Switching Speed 50% control to 10%/90%RF		nsec		3	

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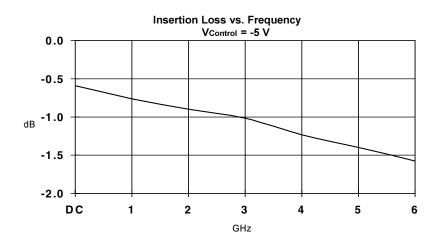


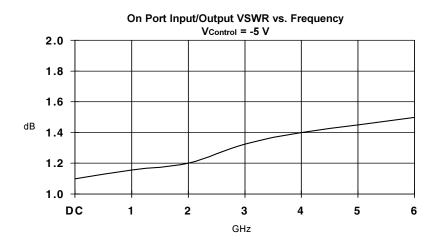
# SSW-224 DC-6.0 GHz GaAs MMIC Switches

# **Absolute Maximum Ratings**

Operation of this device above any one of these parameters may cause permanent damage.

RF Input Power	2W Max>500MHz		
Control Voltage	-10V		
Operating Temperature	-45C to +85C		
Storage Temperature	-65C to +150C		
Thermal Resistance	20 deg C/W		







# Caution ESD Sensitive:

Appropriate precautions in handling, packaging and testing devices must be observed.

# Switch Schematic

# SSW-224 DC-6.0 GHz GaAs MMIC Switches

# **Part Number Ordering Information**

Part Number	Devices Per Reel	Reel Size
SSW-224	500	7"

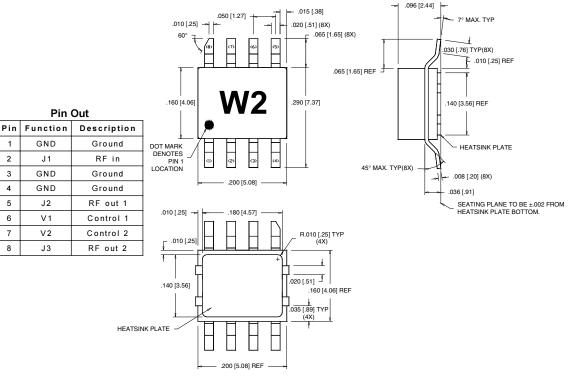
## **Truth Table**

V1	V 2	J1-J2	J1-J3
0	-5	Low Loss	Isolation
-5	0	Isolation	Low Loss

# Part Symbolization

The part will be symbolized with a "W2" designator on the top surface of the package.

# Package Dimensions



DIMENSIONS ARE IN INCHES [MM]